## imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



### DATASHEET

#### 6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER CNY17-X Series CNY17F-X Series



#### Features:

- Current transfer ratios in selected narrow range groups CNY17-1, CNY17F-1: 40-80% CNY17-2, CNY17F-2: 63-125% CNY17-3, CNY17F-3: 100-200% CNY17-4, CNY17F-4:160-320%
- High isolation voltage between input and output (Viso = 5000 Vrms)
- Creepage distance > 7.6 mm
- Operating temperature up to +110°C
- The CNY17F-X series offers no external base connection for minimum noise susceptibility
- · Compact dual-in-line package
- Pb free and RoHS compliant.
- UL approved (No. E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CSA approved

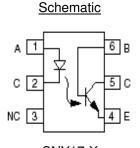
#### Description

The CNY17-X and CNY17F-X series of devices each consist of an infrared emitting diode optically coupled to a phototransistor.

They are packaged in a 6-pin DIP package and available in wide-lead spacing and SMD option.

#### Applications

- Power supply regulators
- Digital logic inputs
- Microprocessor inputs

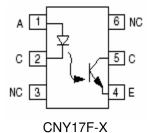


<u>CNY17-X</u>

#### Pin Configuration

- 1. Anode
- 2. Cathode
- 3. No Connection 4. Emitter
- 5. Collector
- 6. Base
- 6. Base





#### Pin Configuration

- 1. Anode
- 2. Cathode
- 3. No Connection
- 4. Emitter
- 5. Collector
- 6. No Connection

Copyright © 2010, Everlight All Rights Reserved. Release Date : May 23, 2013. Issue No: DPC-0000038 Rev. 6

#### Absolute Maximum Ratings (Ta=25℃)

	Parameter	Symbol	Rating	Unit
	Forward current	١ <sub>F</sub>	60	mA
	Peak forward current (t = 10µs)	I <sub>FM</sub>	1	А
Input	Reverse voltage	V <sub>R</sub>	6	V
	Power dissipation ( $T_A = 25^{\circ}C$ )	P <sub>D</sub>	100	mW
	Derating factor (above 100°C)	r <sub>D</sub>	3.8	mW/°C
	Collector-Emitter voltage	$V_{CEO}$	80	V
	Collector-Base voltage*1	V <sub>CBO</sub>	80	V
Outrast	Emitter-Collector voltage	$V_{\text{ECO}}$	7	V
Output	Emitter-Base voltage	$V_{\text{EBO}}$	7	V
	Power dissipation ( $T_A = 25^{\circ}C$ )		150	mW
	Derating factor (above 100°C)	P <sub>C</sub> —	9.0	mW/°C
Total Power	r Dissipation	P <sub>TOT</sub>	200	mW
Isolation vo	ltage <sup>*2</sup>	V <sub>ISO</sub>	5000	V rms
Operating Temperature		T <sub>OPR</sub>	-55 to 110	°C
Storage Temperature		T <sub>STG</sub>	-55 to 125	°C
Soldering to	emperature *3	T <sub>SOL</sub>	260	°C

Notes:

\*1 Only for CNY17-X series.

\*2 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 & 3 are shorted together, and pins 4, 5 & 6 are shorted together.

\*3 For 10 seconds.

#### Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

Input							
Parameter		Symbol	Min.	Тур.	Max.	Unit	Condition
Forward voltage		V <sub>F</sub>	-	-	1.65	V	I <sub>F</sub> = 60mA
Reverse current		I <sub>R</sub>	-	-	10	μA	V <sub>R</sub> = 6V
Input capacitance		C <sub>in</sub>	-	18	-	pF	V = 0, f = 1MHz
Output							
Paramete	er	Symbol	Min	Тур.	Max.	Unit	Condition
Collector-Base dark current	CNY17-X only	I <sub>CBO</sub>	-	-	20	nA	$V_{CB} = 10V, I_F = 0mA$
Collector-Emitter d	ark current	I <sub>CBO</sub>		-	50	nA	$V_{CE}$ = 10V, IF=0mA
Collector-Emitter breakdown voltage		BV <sub>CEO</sub>	80	-	-	V	$I_{\rm C}$ = 1mA, $I_{\rm F}$ = 0mA
Collector-Base breakdown voltage	CNY17-X only	BV <sub>CBO</sub>	80	-	-	V	$I_{\rm C} = 0.1 {\rm mA},$ $I_{\rm F} = 0 {\rm mA}$
Emitter-Collector breakdown voltage	l	$BV_{ECO}$	7	-	-	V	I <sub>E</sub> = 0.1mA, I <sub>F</sub> = 0mA
Collector-Emitter ca	apacitance	$C_{CE}$	-	8	-	pF	VCE = 0V, f =1MHz

\* Typical values at  $T_a = 25^{\circ}C$ 

#### **Transfer Characteristics**

Pa	rameter	Symbol	Min	Тур.	Max.	Unit	Condition
	CNY17-1 CNY17F-1		40	-	80		
Current Transfer	CNY17-2 CNY17F-2	– CTR -	63	-	125	%	I <sub>F</sub> = 10mA ,V <sub>CE</sub> = 5V
Ratio	CNY17-3 CNY17F-3	UIN	100	-	200	/0	$F = 1011A$ , $V_{CE} = 5V$
	CNY17-4 CNY17F-4		160	-	320		
	CNY17-1 CNY17F-1		13	-	-		
Current Transfer	CNY17-2 CNY17F-2		22	-	-		
Ratio	CNY17-3 CNY17F-3	- CTR -	34	-	-	%	$I_{F} = 1 mA$ , $V_{CE} = 5V$
	CNY17-4 CNY17F-4		56	-	-		
Collector-E saturation v		V <sub>CE(sat)</sub>	-	-	0.3	V	$I_F = 10mA$ , $I_C = 2.5mA$
Isolation re	sistance	R <sub>IO</sub>	10 <sup>11</sup>	-	-	Ω	$V_{IO} = 500 V dc$
Input-outpu	t capacitance	C <sub>IO</sub>	-	0.5	-	pF	$V_{IO} = 0, f = 1MHz$
Turn-on tim	е	$T_{on}$	-	10	12		
Turn-off tim	e	$T_{off}$	-	9	12		$V_{\rm CC} = 10V,$
Rise time		Tr	-	6	10		$I_{C} = 2mA, R_{L} = 100\Omega$ See Fig. 11
Fall time		T <sub>f</sub>	-	8	10	μs	
Rise time		Tr	-	2	10		$V_{CC} = 5V, I_F = 10mA,$
Fall time		T <sub>f</sub>	-	3	10		$R_L = 75\Omega$ , See Fig. 11

\* Typical values at  $T_a = 25^{\circ}C$ 

#### DATASHEET **6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER CNY17-X Series CNY17F-X Series**

## EVERLIGHT

#### **Typical Electro-Optical Characteristics Curves**

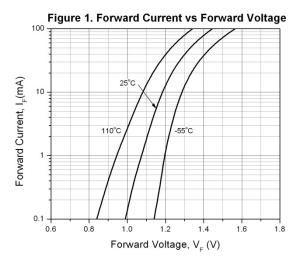


Figure 3. Current Tranfer Ratio vs Ambient Temperature

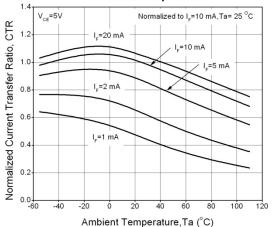


Figure 5. Current Transfer Ratio (Unsaturated) vs Base-Emitter Resistance

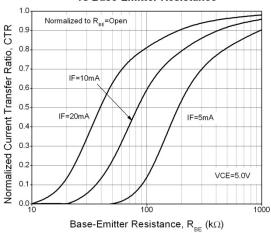


Figure 2. Current Tranfer Ratio vs Forward Current 1.2 Normalized Current Transfer Ratio, CTR 1.0 0.8 0.6 0.4 V<sub>ce</sub>=5 V 0.2 Ta=25°C Normalized to I\_=10 mA 0.0-50 Forward Current, I (mA)

vs Base-Emitter Resistance 1.0 Normalized to R<sub>BE</sub>=Open Normalized Current Transfer Ratio, CTR 0.9 0.8 0.7 I<sub>F</sub>=10mA 0.6 0.5 I<sub>F</sub>=20mA I\_=5mA 0.4 0.3

0.2

0.1

0.0 ¥ 10

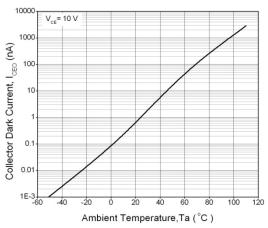
Figure 4. Current Transfer Ratio (Saturated)

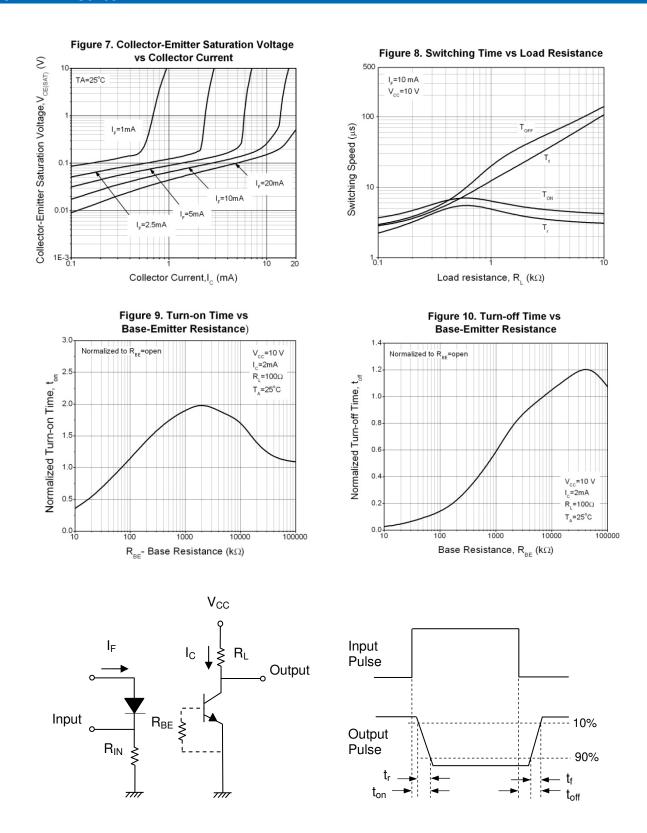
100 Base-Emitter Resistance,  $\textbf{R}_{_{\text{BE}}}$  (k $\Omega)$ 

V<sub>ce</sub>=0.3V

1000









#### **Order Information**

**Part Number** 

CNY17-XY(Z)-V or CNY17F-XY(Z)-V

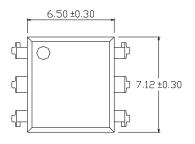
#### Note

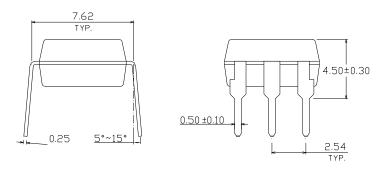
- X Y = Part no. (1, 2, 3 or 4)
- = Lead form option (S, S1, M or none)
- Z V = Tape and reel option (TA, TB or none).
- = VDE (optional)

Option	Description	Packing quantity
None	Standard DIP-6	65 units per tube
М	Wide lead bend (0.4 inch spacing)	65 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	1000 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	1000 units per reel
S1 (TA)	Surface mount lead form (low profile) + TA tape & reel option	1000 units per reel
S1 (TB)	Surface mount lead form (low profile) + TB tape & reel option	1000 units per reel

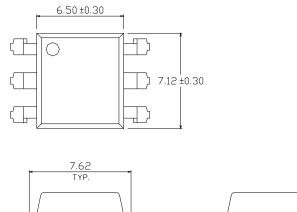
#### Package Dimension (Dimensions in mm)

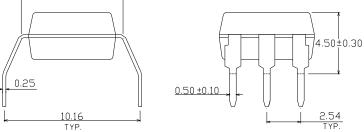
#### Standard DIP Type





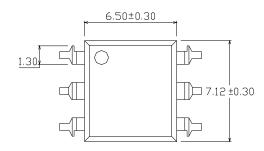
#### **Option M Type**

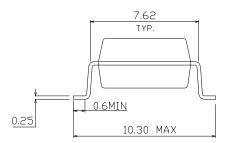


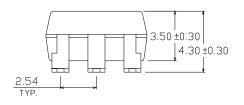




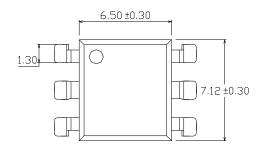
#### **Option S Type**

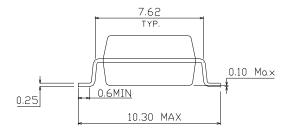


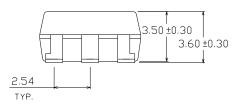




#### **Option S1 Type**

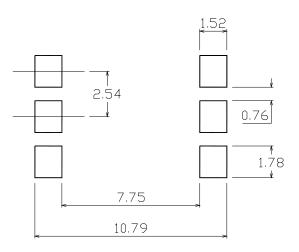




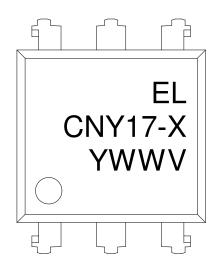




#### Recommended pad layout for surface mount leadform



#### **Device Marking**

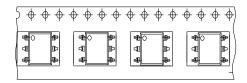


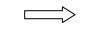
#### Notes

EL	denotes Everlight
CNY17-X	denotes Device Number (X: 1, 2, 3 or 4)
Y	denotes 1 digit Year code
WW	denotes 2 digit Week code
V	denotes VDE (optional)

#### **Tape & Reel Packing Specifications**

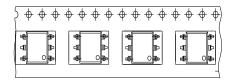
#### Option TA





#### Direction of feed from reel

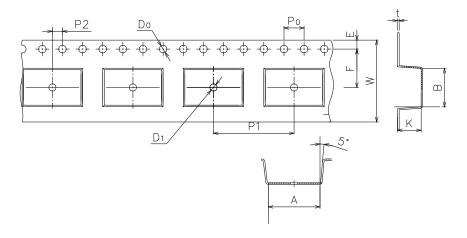
#### Option TB





Direction of feed from reel

#### **Tape dimensions**



Dimension No.	Α	В	Do	D1	E	F
Dimension (mm)	10.4±0.1	7.5±0.1	1.5±0.1	1.5+0.1/-0	1.75±0.1	7.5±0.1
Dimension No.	Ро	P1	P2	t	W	к
Dimension (mm)	4.0±0.15	12±0.1	2.0±0.1	0.35±0.03	16.0±0.2	4.5±0.1

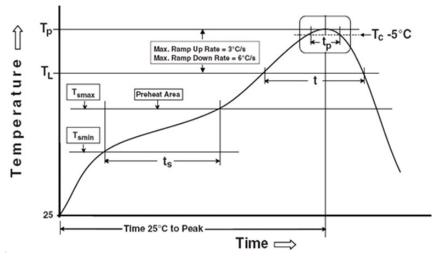


Reference: IPC/JEDEC J-STD-020D

#### **Precautions for Use**

#### 1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

#### Preheat

Temperature min (T <sub>smin</sub> )	150 °C
Temperature max (T <sub>smax</sub> )	200°C
Time ( $T_{smin}$ to $T_{smax}$ ) ( $t_s$ ) Average ramp-up rate ( $T_{smax}$ to $T_p$ )	60-120 seconds 3 °C/second max
Other	
<b>Other</b> Liquidus Temperature (T <sub>L</sub> )	217 °C
	217 °C 60-100 sec

Time within 5 °C of Actual Peak Temperature: T<sub>P</sub> - 5°C

Ramp- Down Rate from Peak Temperature

Time 25°C to peak temperature

**Reflow times** 

.

#### 12 Copyright © 2010, Everlight All Rights Reserved. Release Date : May 23, 2013. Issue No: DPC-0000038 Rev. 6 www.everlight.com

30 s

3 times

6°C /second max.

8 minutes max.

#### DISCLAIMER

- 1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
- 3. These specification sheets include materials protected under copyright of EVERLIGHT corporation. Please don't reproduce or cause anyone to reproduce them without EVERLIGHT's consent.